

INTERNATIONAL STANDARD

NORME INTERNATIONALE

**Semiconductor devices –
Part 15: Discrete devices – Isolated power semiconductor devices**

**Dispositifs à semiconducteurs –
Partie 15: Dispositifs discrets – Dispositifs de puissance à semiconducteurs
isolés**



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SEMICONDUCTOR DEVICES –

Part 15: Discrete devices – Isolated power semiconductor devices

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IEC 60747-15 has been prepared by subcommittee 47E: Discrete semiconductor devices, of IEC technical committee 47: Semiconductor devices. It is an International Standard.

This third edition cancels and replaces the second edition published in 2010. This edition constitutes a technical revision.

This edition includes the following significant technical changes with respect to the previous edition:

- a) The intelligent power semiconductor modules (IPM), which was previously excluded from the first and second edition, is now included in this document (Annex C);
- b) The thermal resistance is described for each switch (6.2.4);
- c) Added isolation test between temperature sensor and terminals, in case there is an agreement with the user (6.1.2).

The text of this International Standard is based on the following documents:

Draft	Report on voting
47E/832/FDIS	47E/844/RVD

Full information on the voting for its approval can be found in the report on voting indicated in the above table.

The language used for the development of this International Standard is English.

This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, available at www.iec.ch/members_experts/refdocs. The main document types developed by IEC are described in greater detail at www.iec.ch/publications.

This International Standard is to be used in conjunction with IEC 60747-1:2006 and Amendment 1: 2010.

A list of all parts in the IEC 60747 series, published under the general title *Semiconductor devices*, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under webstore.iec.ch in the data related to the specific document. At this date, the document will be

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SEMICONDUCTOR DEVICES –

Part 15: Discrete devices – Isolated power semiconductor devices

1 Scope

This part of IEC 60747 gives the requirements for isolated power semiconductor devices. These requirements are additional to those given in other parts of IEC 60747 for the corresponding non-isolated power devices and parts of IEC 60748 for ICs.

2 Normative references

The following documents are referred to in the text in such a way that some or all of their content constitutes requirements of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60068-2-1:2007, *Environmental testing – Part 2-1: Tests – Test A: Cold*

IEC 60270:2015, *High-voltage test techniques – Partial discharge measurements*

IEC 60664-1:2020, *Insulation coordination for equipment within low-voltage systems – Part 1: Principles, requirements and tests*

IEC 60721-3-3:2019, *Classification of environmental conditions – Part 3-3: Classification of groups of environmental parameters and their severities – Stationary use at weather protected locations*

IEC 60747-1:2006, *Semiconductor devices – Part 1: General*
IEC 60747-1:2006/AMD1:2010

IEC 60747-2:2016, *Semiconductor devices – Discrete devices and integrated circuits – Part 2: Rectifier diodes*

IEC 60747-6:2016, *Semiconductor devices – Part 6: Thyristors*

IEC 60747-7:2016, *Semiconductor discrete devices and integrated circuits – Part 7: Bipolar transistors*

IEC 60747-8:2021, *Semiconductor devices – Part 8: Field-effect transistors*

IEC 60747-9:2019, *Semiconductor devices – Discrete devices – Part 9: Insulated-gate bipolar transistors (IGBTs)*

IEC 60748 (all parts), *Semiconductor devices – Integrated circuits*

IEC 60749-5:2017, *Semiconductor devices – Mechanical and climatic test methods – Part 5: Steady-state temperature humidity bias life test*

IEC 60749-6:2017, *Semiconductor devices – Mechanical and climatic test methods – Part 6: Storage at high temperature*